

<b>Connection D</b>	iagram	
Connection D $T/\overline{R}_1 = -$ $B_1 = -$ $B_2 = -$ $B_2 = -$ $B_3 = -$ $B_2 = -$ $B_3 = -$ $B_1 = -$ B	Iagram           1         48           2         47           3         46           4         45           5         44           6         43           7         42           8         41           9         40           10         39           11         38           12         37           13         36           14         35           15         34           16         33           17         32           18         31           19         30           20         29           21         28           22         27           23         26           24         25	$ \begin{array}{c} & A_{0} \\ & A_{1} \\ & GND \\ & A_{2} \\ & A_{3} \\ & V_{CC} \\ & A_{4} \\ & A_{5} \\ & GND \\ & A_{6} \\ & A_{7} \\ & A_{8} \\ & GND \\ & A_{10} \\ & A_{11} \\ & V_{CC} \\ & A_{12} \\ & GND \\ & A_{13} \\ & GND \\ & A_{14} \\ & A_{15} \end{array} $
.,		

#### **Truth Tables**

Inp	uts	
OE <sub>1</sub>	T/R <sub>1</sub>	Outputs
L	L	Bus $B_0 - B_7$ Data to Bus $A_0 - A_7$
L	н	Bus $A_0 - A_7$ Data to Bus $B_0 - B_7$
н	х	HIGH Z State on A <sub>0</sub> –A <sub>7</sub> , B <sub>0</sub> –B <sub>7</sub> (Note 2)
Inp	uts	• • •
$\overline{OE}_2$	T/R <sub>2</sub>	Outputs
L	L	Bus B <sub>8</sub> –B <sub>15</sub> Data to Bus A <sub>8</sub> –A <sub>15</sub>
L	н	Bus A <sub>8</sub> –A <sub>15</sub> Data to Bus B <sub>8</sub> –B <sub>15</sub>
н	Х	HIGH Z State A <sub>15</sub> , B <sub>8</sub> –B <sub>15</sub> (Note 2)
••		

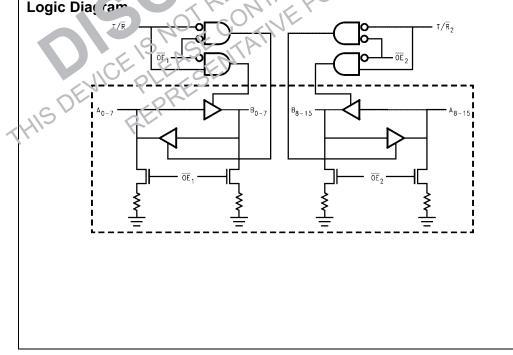
#### **Functional Descriptions**

The LCXP16245 contains sixteen non-inve. hy -Ctional buffers with 3-STATE outputs ie de ei byte controlled. Each byte has separate conpl input, which can be shorted together for full 1/ ... ppen ion. 7 e T/R inputs determine the direction c data flow usuagh the device.

The  $\overrightarrow{OE}$  inputs hable both the A and B ports by placing them in a high impedance state. The pulldown resistor (30K $\Omega$  normal) to Gi (D is active only when the outputs are 3-STATED ( $\overrightarrow{OE} = \text{HiGH}$ ). When the outputs become active ( $\overrightarrow{OE} = \text{LOW}$ ) the resistor is removed from the circuit.

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Symbol	Parameter	Value	Conditions	Units	
′cc	Supply Voltage	-0.5 to +7.0		V	
V <sub>I</sub>	DC Input Voltage	-0.5 to +7.0		V	
Vo	DC Output Voltage	-0.5 to +7.0	Output in 3-STATE	V	
		-0.5 to V <sub>CC</sub> + 0.5	Output in HIGH or LOW State (Note 4)		
IIK	DC Input Diode Current	-50	V <sub>I</sub> < GND	mA	
ОК	DC Output Diode Current	-50	V <sub>O</sub> < GND		
		+50	$V_{O} > V_{CC}$	mA	
0	DC Output Source/Sink Current	±50		mA	
сс	DC Supply Current per Supply Pin	±100		mA	
GND	DC Ground Current per Ground Pin	±100		mA	
Г <sub>STG</sub>	Storage Temperature	-65 to +150		°C	

# **Recommended Operating Conditions**

Recomm	ended Operating C	Conditions			SIG
Symbol	F	Parameter	1in	× -	Units
V <sub>CC</sub>	Supply Voltage	Operating		3.6	v
		Data Pete ion	1.5	3.6	v
VI	Input Voltage		0	5.5	V
Vo	Output Voltage	P'GH _ *ate		V <sub>CC</sub>	V
		3-STATE	0	5.5	$\mathcal{O}$
I <sub>OH</sub> /I <sub>OL</sub>	Output Current	$\overline{V_{CC}}$ $\overline{3.6V}$ $-3.6V$	5	±24	
		V <sub>CC</sub> = 2.7V - 3 6V V <sub>CC</sub> = 2.3V - 2.7V	0	. ₹12	mA
		V <sub>CC</sub> = 2.3V - 2.7V	4-2	±8	
T <sub>A</sub>	Free-Air Operating Temr atu		- 40	85	°C
$\Delta t / \Delta V$	Input Edge Rate, V <sub>IN</sub> = 8V-2	$2.0 V_{CC} = 3.0$	0	10	ns/V

 Note 3: The Absolute Maximum Rating at these limits. The parametric values mended Operating Conditions" with onditions for a stual device operation.
 Note 3: The Absolute Maximum Rating at these limits. The parametric values find in the Elecucal Character stics tables are not guaranteed at the Absolute Maximum Ratings. The "Recommended Operating Conditions" with onditions for a stual device operation.

 Note 4: Io Absolute Maximum I Rating mus.
 Let vice vice vice vice operation.

### DC Electic, 'C'r. acteristics

0	Absolute Maxim Rationmuse	stics				
			V <sub>CC</sub>	$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$		
Symbol	Parameter	Conditions	(V)	Min	Max	Units
′ін	HIGH Level np ut Voltage	05	2.3 - 2.7	1.7		
	A CENTRE		2.7 – 3.6	2.0		V
/IL	LO.V Level Input Voltage		2.3 – 2.7		0.7	V
12.	P QL		2.7 – 3.6		0.8	v
0.1	HIGH Level Output Voltage	$I_{OH} = -100 \ \mu A$	2.3 – 3.6	V <sub>CC</sub> - 0.2		
		$I_{OH} = -8 \text{ mA}$	2.3	1.8		
		$I_{OH} = -12 \text{ mA}$	2.7	2.2		V
		I <sub>OH</sub> = -18 mA	3.0	2.4		
		I <sub>OH</sub> = -24 mA	3.0	2.2		
OL	LOW Level Output Voltage	I <sub>OL</sub> = 100 μA	2.3 - 3.6		0.2	
		I <sub>OL</sub> = 8 mA	2.3		0.6	
		I <sub>OL</sub> = 12 mA	2.7		0.4	V
		I <sub>OL</sub> = 16 mA	3.0		0.4	
		I <sub>OL</sub> = 24 mA	3.0		0.55	
	Input Leakage Current	$0 \leq V_I \leq 5.5 V$	2.3 – 3.6		±5.0	μA
DZ(L)	3-STATE I/O Leakage	$V_{I} \text{ or } V_{O} = 0.0 V$	2.3 - 3.6		±5.0	μA
DZ(H)	3-STATE I/O Leakage	$V_{I} \text{ or } V_{O} = 5.5 V$	2.3 - 3.6	50	500	μA
DFF	Power-Off Leakage Current	$V_{I} \text{ or } V_{O} = 5.5 V$	0		10	μA
C	Quiescent Supply Current	$V_I = V_{CC} \text{ or } GND$	2.3 - 3.6		20	μA
		$3.6V \le V_1, V_0 \le 5.5V$ (Note 5)	2.3 - 3.6	1	±20	μΑ

# 74LCXP16245

#### DC Electrical Characteristics (Continued)

Symbol	Parameter	Conditions	V <sub>CC</sub>	T <sub>A</sub> = -40°0	C to +85°C	Units
0,		Containente	(V)	Min	Max	•
$\Delta I_{CC}$	Increase in I <sub>CC</sub> per Input	$V_{IH} = V_{CC} - 0.6V$	2.3 - 3.6		500	μA

#### **AC Electrical Characteristics**

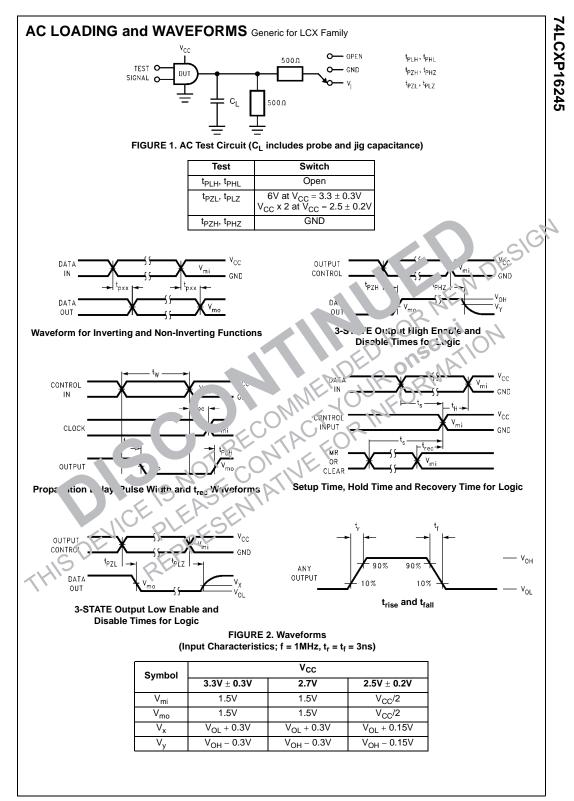
			T <sub>A</sub>	= -40°C to +	85°C, R <sub>L</sub> = 5	00Ω		
Symbol	Parameter	V <sub>CC</sub> = 3.	$3V \pm 0.3V$	V <sub>CC</sub> =	2.7V	VCC = 2.	$5V \pm 0.2V$	Units
Symbol	Faranieter	C <sub>L</sub> =	50 pF	<b>C</b> <sub>L</sub> = 5	50 pF	C <sub>L</sub> = 5	50 pF	Units
		Min	Max	Min	Max	Min	Max	
t <sub>PHL</sub>	Propagation Delay	1.5	5.5	1.5	6.0	1.5	6.6	ns
t <sub>PLH</sub>	A <sub>n</sub> to B <sub>n</sub> or B <sub>n</sub> to A <sub>n</sub>	1.5	5.5	1.5	6.0	15	6.6	115
t <sub>PZL</sub>	Output Enable Time	1.5	7.0	1.5	8.0	1.5	9.1	ns
t <sub>PZH</sub>		1.5	7.0	1.5	8.0	1.5	9.1	
t <sub>PLZ</sub>	Output Disable Time	1.5	7.0	1.5	0		8,4	ns
t <sub>PHZ</sub>		1.5	7.0	1.5	7.	1.5	8.4	115
t <sub>OSHL</sub>	Output to Output Skew (Note 6)		1.0				9	ns
t <sub>OSLH</sub>			1.0			NE		115

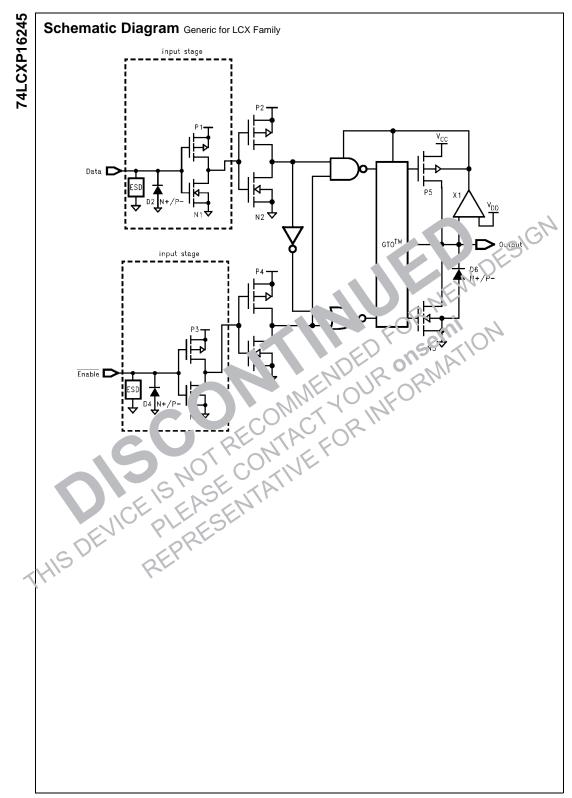
natil dela ...iy two separale outputs of the same device. The LOW-to-H'Gr' ('OSLH). Para neter guaranteed by design. Note 6: Skew is defined as the absolute value of the difference between the actual specification applies to any outputs switching in the same direction, either HIC 'o-L 'o-L' sen

## Dynamic Switching Characteris

Symbol	Parameter		T <sub>A</sub> = 25°C	Units
Cymber		(V)	Typical	onto
V <sub>OLP</sub>	Quiet Output Dynamic Peak $J_L$ $C_L = 50 \text{ pF}, V_{1H} = 3.3 \text{ V}, V_{1L} = 3 \text{ V}$		0.8	V
	$C_{L} = 30 \text{ pr}$ ; $V_{H} = 2.5 \text{ V}$ ; $V_{IL} = 0 \text{ V}$	2.5	0.6	v
V <sub>OLV</sub>	Quiet Output Dyn inc Valley . $C_L = 50 \text{ pF}, V_{IH} = 3.3 \text{V}, V_{II} = 9 \text{V}$		-0.8	V
	$C_{L} = 30 \text{ p}^{-1} \text{ V}_{H} = 2.5 \text{ V}, \text{ V}_{H} = 0 \text{ V}$	2.5	-0.6	v
Capac	siton.			

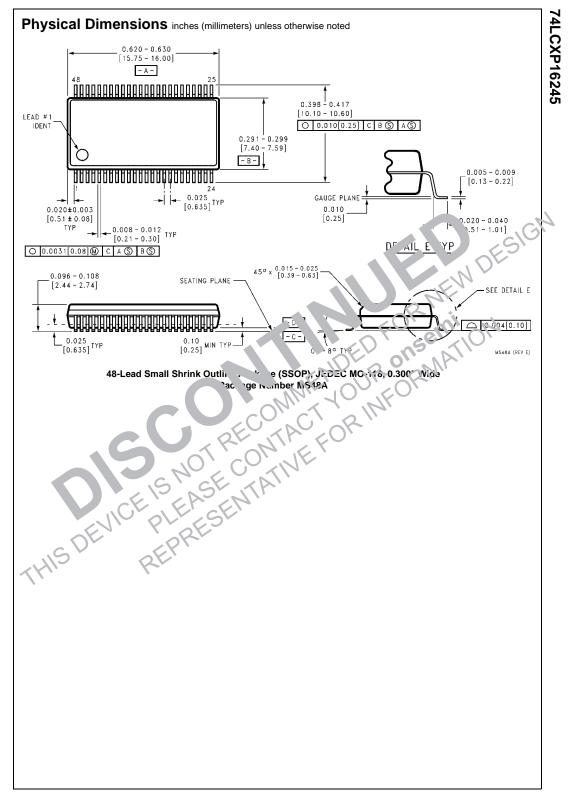
Sym'	Parameter	Conditions	Typical	Units
	,-acitance	$V_{CC} = Open, V_I = 0V \text{ or } V_{CC}$	1	pF
C <sub>I/O</sub> I ut/Ou	Itout Capacitance	$V_{CC} = 3.3 V$ , $V_I = 0 V$ or $V_{CC}$	8	pF
C <sub>PD</sub> Powel L	issipation Capacitance	$V_{CC} = 3.3V, V_{I} = 0V \text{ or } V_{CC}, f = 10 \text{ MHz}$	20	pF
	OV			
K	K.			

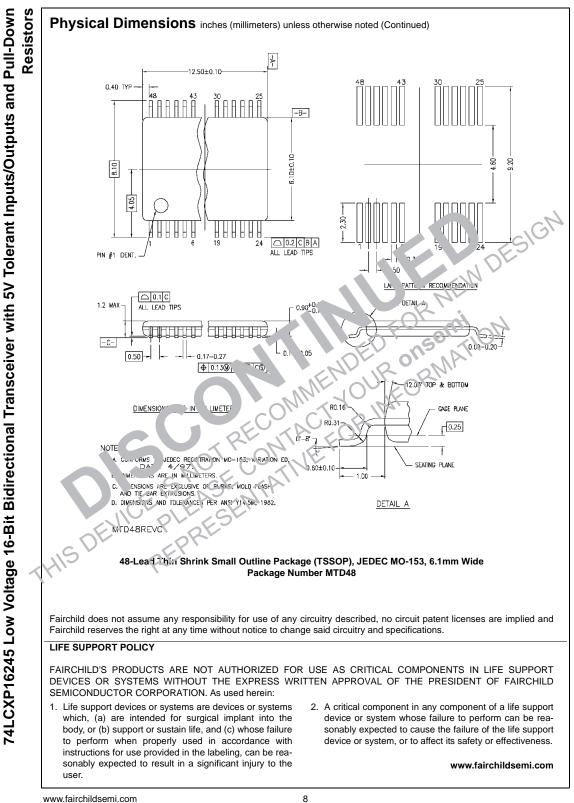




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